

## U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE FEE RECORD SHEET

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\*U S. GPO: 2000-468-987/39595

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Reissue Application of:

URANO et al.

U.S. Patent No.

5,216,135

Issue Date:

June 1, 1993

For:

**DIAZODISULFONES** 

#### **OFFER TO SURRENDER**

Director of Patents and Trademarks Washington, D.C. 20231

March 15, 2001

Sir:

The undersigned, attorney of record in the U.S. Patent No. 5,216,135, hereby offers to surrender said Letters Patent in connection with the accompanying reissue application.

Submitted herewith is a Request For Title Report, as required in this reissue application.

In the event any fees are required in connection with this paper, please charge our Deposit Account No. 01-2340.

Respectfully submitted,

ARMSTRONG, WESTERMAN, HATTORI,

McLELAND & NAUGHTON, LLP

James E. Armstrong, IV Attorney for Applicants Reg. No. 42,266

Atty. Docket No. 910094RE

Suite 1000

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Fax: (202) 887-0357 JAM/plb:lms

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U.S. Patent No.

5,216,135

Issue Date:

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**DIAZODISULFONES** 

#### **ASSENT OF ASSIGNEE**

The undersigned, who is empowered to act on behalf of WAKO PURE CHEMICAL INDUSTRIES, LTD. which is the assignee to the entire right, title and interest in United States Patent No. 5,216,135, issued June 1, 1993, hereby assents to the filing of the above-identified application for reissue of said patent.

WAKO PURE CHEMICAL INDUSTRIES, LTD.

Date: **Much 13**, 200

By: \_\_

Name: Dajim

Title:

President

H \HOME\LINDAS\JAM\91\910094RE\ASSENT OF ASSIGNEE

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re	the Re	issue A	pplication of:
UR	ANO et	al.	
U.S.	Patent	No.	5,216,135
Issu	e Date:		June 1, 1993
For:			DIAZODISULFONES
			CERTIFICATE UNDER 37 CFR § 3.73(b)
WAI of th	e entire	right, t  ] An a  assig	EMICAL INDUSTRIES, LTD., a corporation, certifies that it is the assignee itle and interest in the patent identified above by virtue of either:  assignment from the inventor(s) of the patent identified above. The gament was recorded in the Patent and Trademark Office at Reel 5585, Frame 460, or for which a copy thereof is attached
OR		·	, and a specific and a second a
В.	[]	A ch	ain of title from the inventor(s), of the patent application identified above, to urrent assignee as shown below:
		1.	From: To:
		2.	From: To: The document was recorded in the Patent and Trademark Office at Reel, Frame, or for which a copy thereof is attached.
		3.	From: To: To: The document was recorded in the Patent and Trademark Office at Reel, Frame, or for which a copy thereof is attached.
	/	[]	Additional documents in the chain of title are listed on a supplemental sheet.
		[]	Copies of assignments or other documents in the chain of title are attached.

SCANNED, # 14

The undersigned has reviewed all the documents in the chain of title of the patent application identified above and, to the best of undersigned's knowledge and belief, title is in the assignee identified above.

The undersigned (whose title is supplied below) is empowered to act on behalf of the assignee.

I hereby declare that all statements made herein of my own knowledge are true and that statements made on information and belief are believed to be true; and further, that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

WAKO PURE CHEMICAL INDUSTRIES, LTD.

Date: March 13 2001

By:

Name: Hajime Ikezoe

Title:

President

H \HOME\LINDAS\JAM\91\910094RE\CERTIFICATE 37 CFR 3 73B







## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

the Reissue Application of:

URANO et al.

U.S. Patent No.

5,216,135

Issue Date:

June 1, 1993

For:

Sir:

**DIAZODISULFONES** 



#### **AMENDMENT TRANSMITTAL**

Director of Patents and Trademarks Washington, D.C. 20231

March 15, 2001

Transmitted herewith is an application for reissue of U.S. Patent No. 5,216,135.

The Applicants of this reissue application are the inventors:

Fumiyoshi URANO;

Masaaki NAKAHATA;

Hirotoshi FUJIE; and

- Keiji OONO

#### Enclosed are:

- (1) Reissue specification and claims
- (2) Offer to Surrender
- (3) Assent of Assignee
- (4) Request for Title Report
- (5) Preliminary Amendment

#### The fee has been calculated as shown below:

CLAIMS AS AMENDED								
Claims Remaining After Highest Number Previously Present Small Large Amendment Paid For Extra Entity Entity								
Total Claims	X \$9	X \$18						
Independent Claims	3	3	=	0	X \$40	X \$80		
## First Presentation of Multiple Dependent Claims \$135 270								
TOTAL FEES ENCLOSED:								

Enclosed is a check in the amount of \$735.00 for the filing fee of \$710.00 and the fee for the Title Report of \$25.00. Please charge any additional fees which may be required, or credit any overpayment to our Deposit Account NO. 01-2340.

Respectfully submitted,

ARMSTRONG, WESTERMAN, HATTORI, McLELAND & NAUGHTON, LLP

James E. Armstrong, IV Attorney for Applicants Reg. No. 42,266

Atty. Docket No. 910094RE

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JAM/plb:lms

H \HOME\LINDAS\JAM\91\910094ri Reissue Application\REISSUE TRANSMITTAL

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Reissue Application of:

URANO et al.

U.S. Patent No.

5,216,135

Issue Date:

June 1, 1993

For:

**DIAZODISULFONES** 

## PRELIMINARY AMENDMENT

Director of Patents and Trademarks Washington, D.C. 20231

March 15, 2001

Sir:

Prior to calculation of the filing fee and examination of this reissue application, please amend the reissue application as follows:

## **FN THE CLAIMS**:

Please cancel claims 1-6 and amend claim 7 as follows:

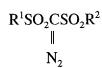
7. (Amended) A diazodisulfone compound of the formula:

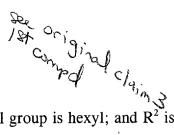
$$R^1$$
-SO<sub>2</sub>CSO<sub>2</sub>- $R^2$ 
 $\parallel$ 
 $N_2$ 

wherein R<sup>1</sup> is a branched alkyl group having 3 to 8 carbon atoms; and R<sup>2</sup> is a cyclic alkyl group having 3 to 8 carbon atoms.

### Please add new claims 8 and 9 as follows:

8. A diazodisulfone compound of the formula;

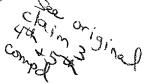




wherein  $R^1$  is a cyclic alkyl group in which the alkyl group is hexyl; and  $R^2$  is a cyclic alkyl group in which the alkyl group is hexyl.

9. A diazodisulfone compound of the formula;





where R<sup>1</sup> is a branched alkyl group in which the alkyl group is butyl; and R<sup>2</sup> is a branched alkyl group in which the alkyl group in which the alkyl group is butyl.

## **REMARKS**

Claims 7 and new claims 8 and 9 are pending in this application.

An adverse decision from the United States Court of Appeals for the Federal Circuit, *In*re Wako Pure Chemical Industries Ltd., No. 00-1139 (Fed. Cir. February 1, 2001), an appeal

from Ex parte Wako Pure Chemical Industries Ltd., No. 1999-1971 (Bd. Pat. App. Int'f

September 24, 1999) of reexamination No. 90/004,812, warrants the cancellation of claims 1-6.

In reexamination the Board sustained the Examiner's rejection of claims 1 and 4-6 under 35 USC

§ 102(e) and 103(a) over US Patent No. 5,338,641 to Pawlowski et al. Claims 2-3 were also

rejected and not appealed.

Claim 7, still in force, has been amended to be in independent form.

New claims 8 and 9 are supported in the reissue specification as follows (col 2, lines 32-

48:

1

In the formula (I), the alkyl group in the definition of R¹ includes, for example, an isopropyl group, an isobutyl group, a sec-butyl group, a 2-methyl-2-butyl group, a 1,1-dimethylbutyl group, a 2-methylbutyl group, a 1,1-dimethylbutyl group, a 2-hexyl group, a cyclopentyl group, a cyclohexyl group, a cyclohexyl group, a cyclohexyl group, a cycloheptyl group, a cycloheptyl group, a cycloheptyl group, a cycloheptyl group, a methyl group, an ethyl group, a n-propyl group, an isopropyl group, a cyclopropyl group, an isobutyl group, a secbutyl group, a tert-butyl group, an n-amyl group, an isobutyl group, a secbutyl group, a tert-butyl group, a 2-methyl-2-butyl group, a cyclopentyl group, a n-hexyl group, a cyclohexyl group, a n-heptyl group, a n-octyl group, etc. (emphasis added).

The recitation of a n-butyl group, an isobutyl group, a sec-butyl group, a tert-butyl group is a recitation of all possible configurations of a branched butyl configuration.

New claims 8 and 9 are supported in the priority document of the reissue specification as follows (certified translation, p.14, lines 5-10.)

In the photosensitive compound represented by the formula [I] of this invention, as the straight-chain, branched or cyclic alkyl group or the alkyl group in the haloalkyl group represented by  $R^1_o$  and  $R^2_o$ , there are included  $C_{1-10}$  alkyl groups such as methyl, ethyl, propyl, *butyl*, amyl, *hexyl*, octyl, and decyl group. (Emphasis added).

The new claims are of narrower scope than the original claims and are fully supported in the reissue specification and the priority document dated January 30, 1990. Because of the priority date, claim 7, still in force, and new claims 8 and 9 outside the scope of any prior art

cited in the parent patent US Pat. No. 5,216, 135.

If, for any reason, it is believed that this application is not now in condition for allowance, the Examiner is requested to contact Applicant's undersigned attorney at the telephone number indicated below to arrange for an interview to expedite the disposition of this case.

In the event that this paper is not timely filed, Applicant respectfully petitions for an appropriate extension of time. The fees for such an extension or any other fees which may be due with respect to this paper, may be charged to Deposit Account No. 01-2340.

Respectfully submitted,

ARMSTRONG, WESTERMAN, HATTORI,

McLELAND & NAUGHTON, LLP

James E. Armstrong, IV. Attorney for Applicant(s)

Reg. No. 42,266

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JAM/lms

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## **VERSION WITH MARKINGS SHOWING CHANGES**

7. (Amended) [The compound according to claim 4] A diazodisulfone compound of the formula:

$$\begin{matrix} R^1\text{-SO}_2\text{CSO}_2\text{-}R^2 \\ \parallel \\ N_2 \end{matrix}$$

wherein  $R^1$  is a branched alkyl group having 3 to 8 carbon atoms; and  $R^2$  is a cyclic alkyl group having 3 to 8 carbon atoms.



## United States Patent [19]

Urano et al.

5,216,135 Patent Number:

Date of Patent: [45]

Jun. 1, 1993

[54]	DIAZODISULFONES					
[75]	Inventors:	Fumiyoshi Urano, Niiza; Masaaki Nakahata, Kawagoe; Hirotoshi Fujie, Saitama; Keiji Oono, Sakado, all of Japan				
[73]	Assignee:	Wako Pure Chemical Industries, Ltd., Osaka, Japan				
[21]	Appl. No.:	962,089				
[22]	Filed:	Oct. 16, 1992				
	Relat	ted U.S. Application Data				
[63]	Continuation doned.	n of Ser. No. 646,909, Jan. 28, 1991, aban-				
[30]	Foreign	Application Priority Data				

Foreign Application Priority Data Jan. 30, 1990 [JP] Japan ..... 2-019614

[51] Int. Cl.<sup>5</sup> ...... C07C 245/12; C07C 245/16 [52] U.S. Cl. ...... 534/556; 534/558; 534/565

[58] Field of Search ...... 534/556, 558, 565

[56] References Cited

#### U.S. PATENT DOCUMENTS

3,332,936	7/1967	Diekmann	534/556
4,491,628	1/1985	Ito et al	430/176
4,603,101	7/1986	Crivello	430/270

#### FOREIGN PATENT DOCUMENTS

2-27660 3/1984 Japan . 62-115440 5/1987 Japan . 1231789 5/1987 United Kingdom

#### OTHER PUBLICATIONS

Chem. Abstract, 68 (13):59304j. Chemical Abstracts, 60, 19928h (1984). Chemische Berichte Jahrg., 97, 735 (1964). Polymer Engineering and Science, Dec. 1983, vol. 23, No. 18, pp. 1012-1018. SPIE, 920, p. 67 (1988).

Chemische Berichte Jahrg., 99, 1966, vol. 9, No. 5 pp. 1704-1711.

J. Chem. Soc. Perkin Trans. II No. 10 pp. 1273-1278 (1982).

Chemical Abstracts, 114, 33140w (1991).

Primary Examiner-Marianne M. Cintins Assistant Examiner-John D. Peabody Attorney, Agent, or Firm-Armstrong, Westerman, Hattori, McLeland & Naughton

**ABSTRACT** 

wherein R1 is a C3-8 branched or cyclic alkyl group, and R<sup>2</sup> is a C<sub>1-8</sub> straight-chain, branched or cyclic alkyl group, is effective as a photoacid generator when used in a photoresist material for light of 300 nm or less.

7 Claims, 2 Drawing Sheets





#### DIAZODISULFONES

This application is a continuation of application Ser. No. 646,909 filed Jan. 28, 1991 now abandoned.

#### BACKGROUND OF THE INVENTION

This invention relates to a diazodisulfone compound useful as a photosensitive material for deep ultraviolet larly, the present invention relates to a diazodisulfone compound which generates an acid by irradiating with KrF excimer laser light (248.4 nm), ArF excimer laser light (193 nm), electron beams, X-rays, etc.

With recent higher density and larger scale integration of semiconductor devices, wavelengths used in exposing devices for minute processing, particularly for lithography become shorter and shorter. Now, KrF excimer laser light (248.4 nm) is studied. In order to use 20 the KrF excimer laser as a light source, a resist material is required to act highly sensitively to light exposed.

One method for making the resist material highly sensitive is to contain therein a compound which has a property of generating an acid when exposed to light, 25 that is, to use a so-called chemical amplified resist material [e.g. H. Ito et al: Polym. Eng. Sci., vol. 23, 1012 (1983)]. As the compound generating an acid by exposing to light (heremafter referred to as "photoacid generator"), there are proposed onium salts such as allyl 30 diazonium salts, diallyl iodonium salts, triallyl sulfonium salts (e.g. U.S. Pat. Nos. 4,491,628 and 4,603,101, Japanese Patent Examined Publication No. 2-27660, Japanese Patent Unexamined Publication No. 62-115440), 2,6-dinitrobenzyl tosylate [e.g. F.M. Houli- 35 han, et al: SPIE, vol. 920, Advances in Resist Technology and Processing V, page 67 (1988)]. But, since these compounds used as the photoacid generator have aromatic rings, there is a problem in that resist materials containing these compounds lower transmittance for 40 light. Further, in the case of onium salts, resist materials containing onium salts have a problem in that the resist materials are poor in solution stability during storage.

Therefore, a resist material overcoming the problem of poor solution stability caused by a property of 45 photoacid generator, and improving transmittance for deep UV light and KrF excimer laser light is desired.

#### SUMMARY OF THE INVENTION

It is an object of the present invention to provide a diazodisulfone compound used as an photoacid generator overcoming the problems mentioned above, having high transmittance for light of 300 nm or less, e.g. deep UV light, KrF excimer laser light, ArF excimer laser 55 light, generating easily an acid by exposure to the light mentioned above or by irradiation with electron beams, X-rays, etc., being excellent in solution stability in the resist material, and having a function of improving a dissolution inhibiting effect of the resist material for an 60 alkali developing solution.

The present invention provides a diazodisulfone compound of the formula:

wherein R1 is a branched or cyclic alkyl group having 3 to 8 carbon atoms; and R2 is a straight-chain, branched or cyclic alkyl group having 1 to 8 carbon atoms.

#### BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a graph showing a UV spectral curve of an acetonitrile solution of bis-cyclohexylsulfonyl diazomethane obtained in Example 1.

FIGS. 2(a) to 2(c) are schematic cross-sectional views (UV) light, electron beams, X-rays, etc. More particu- 10 explaining a positive tone pattern forming process using a resist material containing the compound of the present invention as an photoacid generator.

#### DESCRIPTION OF THE PREFERRED **EMBODIMENTS**

The diazodisulfone compound of the formula:

$$R^1SO_2CSO_2R^2$$
 (I)  $N_2$ 

wherein R1 is a branched or cyclic alkyl group having 3 to 8 carbon atoms; and R<sup>2</sup> is a straight-chain, branched or cyclic alkyl group having 1 to 8 carbon atoms, has high transmittance for light of 300 nm or less, e.g. deep UV light, KrF excimer laser light, etc., generates an acid easily by exposure to such light or by irradiation with electron beams, X-rays, etc., the acid generated functioning effectively on chemical amplification of the resist material with heating, and is excellent by itself in solution stability in the resist material.

In the formula (I), the alkyl group in the definition of R1 includes, for example, an isopropyl group, an isobutyl group, a sec-butyl group, a tert-butyl group, an isoamyl group, a see amyl group, a 2-methylbutyl group, a 2-methyl-2-butyl group, a 1,1-dimethylbutyl group, a 2-hexyl group, a 1,1-dimethylpentyl group, a 1,1-dimethylhexyl group, a cyclopropyl group, a cyclopentyl group, a cyclohexyl group, a cycloheptyl group, a cyclooctyl group, etc. The alkyl group in the definition of R<sup>2</sup> includes, for example, a methyl group, an ethyl group, a n-propyl group, an isopropyl group, a cyclopropyl group, a n-butyl group, an isobutyl group, a sec-butyl group, a tert-butyl group, an n-amyl group, an isoamyl group, a sec-amyl group, a 2-methylbutyl group, a 2-methyl-2-butyl group, a cyclopentyl group, a n-hexyl group, a cyclohexyl group, a n-heptyl group, a n-octyl group, etc.

Preferable examples of the diazodisulfones of the 50 formula (I) are as follows.

Bis(cyclohexylsulfonyl)diazomethane Cyclohexylsulfonylethylsulfonyldiazomethane Bis(isopropylsulfonyl)diazomethane Bis(tert-butylsulfonyl)diazomethane Bis(sec-butylsulfonyl)diazomethane tert-Butylsulfonylmethylsulfonyldiazomethane tert-Butylsulfonylcyclohexylsulfonyldiazomethane Bis(cyclopentylsulfonyl)diazomethane Cyclopentylsulfonyl-tert-butylsulfonyldiazomethane Bis(isoamylsulfonyl)diazomethane, etc.

The compound of the formula (I) has a bulky group of a branched or cyclic alkyl group at at least one of R1 (1) 65 and R<sup>2</sup>, so that it per se has a property of low insolubility in an alkali developing solution. Therefore, a resist material containing such a compound is consequently lowered in solubility in an alkali developing solution. -1

resulting in increasing a dissolution inhibiting effect on so-called non-exposed portions. Such a resist material is more preferable as a pattern forming material.

On the other hand, when both R<sup>1</sup> and R<sup>2</sup> in the formula (I) have no bulky groups in contrast to the definitions in the present invention, for example, R<sup>1</sup> and R<sup>2</sup> are ethyl groups, such a compound has a property of generating an acid by exposure to KrF excimer laser light, and also has a property of being dissolved by itself in the alkali developing solution used for pattern formation. Thus, when such a compound is used as an photoacid generator in a chemical amplified resist material and subjected to pattern formation, both exposed portions and non-exposed portions are dissolved in the alkali developing solution, resulting in failing to conduct good pattern formation.

The compound of the formula (I) can be synthesized easily as follows.

For example, when  $R^1 = R^2$ , the compound of the formula (I) can be synthesized by the following reaction scheme (1):

$$\begin{array}{c} \text{CR}^{1}\text{SH} \xrightarrow{\text{CH}_{2}\text{Cl}_{2}} & \text{R}^{1}\text{SCH}_{2}\text{SR}^{1} \xrightarrow{\text{H}_{2}\text{O}_{2}} \end{array}$$
(II) (III)

$$R^{1}SO_{2}CH_{2}SO_{2}R^{1} \xrightarrow{CH_{3}} R^{1}SO_{2}CSO_{2}R^{1} \xrightarrow{base} R^{1}SO_{2}CSO_{2}R^{1}$$

$$(1V)$$

$$(V)$$

This is explained in detail as follows. The compound of the formula:

wherein R<sup>1</sup> is as defined above, is reacted with methylene chloride in an organic solvent in the presence of a base to yield the compound of the formula:

$$R^1SCH_2SR^1$$
 (III) 45

wherein R1 is as defined above.

As the base, there can be used NaOH, KOH, NaH, sodium methoxide, sodium ethoxide, pyridine, piperidine, morpholine, triethylamine, N-methylpyrrolidine, 50

As the organic solvent, there can be used alcohols such as methanol, ethanol, propanol, isopropenol, etc.; aromatic hydrocarbons such as benzene, toluene, etc.; cyclic ethers such as 1,4-dioxane, tetrahydrofuran (THF), etc.

Methylene chloride is used usually in an amount of 1 to 20 moles, preferably 5 to 15 moles, per mole of the compound of the formula (I).

The reaction is carried out usually at 20° to 100° C., preferably at 25° to 65° C. for usually 1 to 20 hours, 60 preferably 2 to 10 hours.

The resulting compound of the formula (III) is purified by a conventional method.

The compound of the formula (III) is, then, reacted with hydrogen peroxide in a solvent in the presence of 65 a catalyst to yield the compound of the formula:

$$R^{\dagger}SO_2CH_2SO_2R^{\dagger}$$
 (IV)

wherein R1 is as defined above.

The hydrogen peroxide is used usually in an amount of 1 to 10 moles, preferably 2 to 6 moles, per mole of the compound of the formula (III).

As the catalyst, there can be used sodium tungstate, ammonium phosphomolibdate, etc.

As the solvent, there can be used water; alcohols such as methanol, ethanol, propanol, isopropanol, etc.; a mixed solvent of water and an alcohol, etc.

The reaction is carried out usually at 0° to 100° C., preferably at 20° to 80° C., for usually 1 to 20 hours, preferably 1 to 10 hours.

The resulting compound of the formula (IV) is purified by a conventional method.

Then, the compound of the formula (IV) is reacted with tosyl azide in a solvent in the presence of a base to yield the compound of the formula:

wherein R1 is as defined above.

The tosyl azide is used usually in an amount of 0.5 to 5 moles, preferably 0.5 to 2 moles, per mole of the compound of the formula (IV).

As the base, there can be used NaOH, KOH, NaH, sodium methoxide, sodium ethoxide, pyridine, piperidine, morpholine, triethylamine, N-methylpyrrolidine, etc.

As the solvent, there can be used water; water-soluble organic solvents such as methanol, ethanol, propanol, isopropanol, acetone, 1,4-dioxane, etc.; and a mixed solvent of water and a water-soluble organic solvent.

The reaction is carried out usually at 0° to 50° C., preferably at 5° to 30° C., for usually 1 to 20 hours, preferably 1 to 10 hours.

The resulting compound of the formula (V) is purified by a conventional method.

When  $R^1$  and  $R^2$  are different, the compound of the formula (I) can be synthesized easily by the following reaction scheme (2):

$$R^{1}SH \xrightarrow{\{CH_{2}O\}_{H}} R^{1}SCH_{2}CI \xrightarrow{R^{2}SCH} R^{1}SCH_{2}SR^{2} \xrightarrow{H_{2}O_{2}} R^{1}SCH_{2}SR^{2} \xrightarrow{H_{2}O_{2}} R^{1}SCH_{2}SR^{2} \xrightarrow{H_{2}O_{2}} R^{1}SO_{2}CSO_{2}R^{2} \xrightarrow{Dasc} R^{1}SO_{2}CSO_{2}R^{2} \xrightarrow{N_{2}O_{2}CSO_{2}R^{2}} R^{1}SO_{2}CSO_{2}R^{2}$$

This is explained in detail as follows.

The compound of the formula (II) in an amount of 1 mole is mixed with usually 0.5 to 10 moles, preferably 0.5 to 2 moles of paraformaldehyde (e.g. n=3), followed by introduction of HCl gas in an amount of equimolar or mole of the paraformaldehyde at usually 10° C. or lower, preferably  $-10^{\circ}$  to  $+5^{\circ}$  C. Then, anhydrous calcium chloride is added to the resulting mixture to carry out the reaction at usually 10° C. or lower, preferably  $-10^{\circ}$  to  $+5^{\circ}$  C., for usually 1 to 20 hours, prefera-

wherein R1 is as defined above.

The compound of the formula (VI) is then reacted with the compound of the formula:

wherein  $R^2$  is as defined above but different from  $R^1$ , in a solvent in the presence of a base to yield the compound of the formula:

$$R^1SCH_2SR^2$$
 (VIII)

The compound of the formula (VI) is used in an amount of usually 0.5 to 5 moles, preferably 0.5 to 2 moles, per mole of the compound of the formula

As the base, there can be used NaOH, KOH, NaH, sodium methoxide, sodium ethoxide, etc.

As the solvent, there can be used alcohols such as methanol, ethanol, isopropanol, etc.

The reaction is carried out usually at 0° to 50° C., <sup>25</sup> preferably at 0° to 20° C., for usually 1 to 20 hours, preferably 1 to 10 hours.

The resulting compound of the formula (VIII) is purified by a conventional method.

The compound of the formula (VIII) is oxidized with hydrogen peroxide, followed by diazotization with tosylazide, in the same manner as described in the reaction scheme (1) to yield the compound of the formula (I).

The compound of the formula (VIII) can also be synthesized by the following reaction scheme (3):

$$R^{1}SH + R^{2}SH \xrightarrow{CH_{2}Cl_{2}} R^{1}SCH_{2}SR^{2} \xrightarrow{H_{2}O_{2}}$$
(II) (VII) (VIII)

$$R^{1}SO_{2}CH_{2}SO_{2}R^{2} \xrightarrow{base} R^{1}SO_{2}CSO_{2}R^{2}$$

$$\downarrow N_{2}$$

This is explained in detail as follows.

The compound of the formula (II) is reacted with the compound of the formula (VII) and methylene chloride in a solvent in the presence of a base to yield the compound of the formula (VIII).

The compound of the formula (VII) is used usually in an amount of 0.5 to 5 moles, preferably 0.5 to 2 moles, per mole of the compound of the formula (II), and methylene chloride is used usually in an amount of 1 to 60 20 moles, preferably 5 to 15 moles, per mole of the compound of the formula (II).

As the base, there can be used NaOH, KOH, NaH, sodium methxoide, sodium ethoxide, pyridine, piperidine, morpholine, triethylamine, N-methylpyrrolidine, 65

As the solvent, there can be used alcohols such as methanol, ethanol, propanol, isopropanol, etc.; aro-

matic hydrocarbons such as benzene, toluene, etc.; cyclic ethers such as 1,4-dioxane, tetrahydrofuran, etc.

The reaction is carried out usually at 20° to 100° C., preferably 25° to 65° C. for usually 1 to 20 hours, preferably 2 to 10 hours.

The resulting product is purified by a conventional method such as distillation, column chromatography, etc. to yield the compound of the formula (VIII).

The compound of the formula (VIII) is converted to (VII) 10 the compound of the formula (I) in the same manner as described in the reaction scheme (2).

When R<sup>1</sup> and R<sup>2</sup> are different, the reaction scheme (2) is preferable from the viewpoint of practical production.

The compound of the formula (I) is effectively used in a chemical amplified resist material wherein there is used a polymer having a property of alkali-soluble by the action of an acid. When the resist material is exposed to KrF excimer laser light or the like, the compound of the formula (I) present in the exposed portion generates an acid by the following reaction scheme (4):

$$R^{1}SO_{2}CSO_{2}R^{2} \xrightarrow{h\nu} R^{1}SO_{2}CSO_{2}R^{2} \xrightarrow{2) H_{2}O}$$

When heat treatment is applied after the exposure step, functional groups of the polymer in the resist material is subjected to a chemical change by the acid to become alkali-soluble by the following reaction scheme (5):

$$\begin{array}{c}
CH-CH_2 \\
\hline
OC(CH_3)_3
\end{array}$$

$$\begin{array}{c}
H^+ \\
\Delta
\end{array}$$

The resulting alkali-soluble polymer is released into an alkali developing solution at the time of development.

On the other hand, since non-exposed portions do not generate an acid, no chemical change takes place even if heat treated to produce no alkali-soluble groups. Further, since the compound of the formula (I) has a dissolution inhibiting effect, the non-exposed portions become difficultly soluble in the alkali developing solution.

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As mentioned above, when pattern formation is carried out by using a chemical amplified resist material containing the compound of the formula (I), a large difference in solubility in the alkali developing solution takes place between the exposed portions and the non-exposed portions. As a result, there can be formed a positive tone pattern having good contrast. Further, as is clear from the reaction scheme (5), since the acid generated by exposure to light acts catalytically, not only the necessary amount of acid can be produced by the exposure to light, but also the light exposure energy amount can be reduced.

Needless to say, the compound of the formula (I) is useful for producing semiconductors and can be used as 15 a photosensitive reagent in the field of applying photo reaction such as photograving, printing plate materials,

The present invention is illustrated by way of the following Examples.

#### REFERENCE EXAMPLE 1

#### (1) Free radical polymerization of p-tert-butoxystyrene

A solution of p-tert-butoxystyrene (17.6 g) in toluene 25 containing catalytic amount of 2,2'-azobisisobutyronitrile (AIBN) was heated at 80° C. for 6 hours under nitrogen. After cooling, the reaction mixture was poured into methanol and the polymer was precipitated. The polymer was filtered, washed with methanol and dried under reduced pressure to afford 15.5 g of poly(p-tert-butoxystyrene) as white powders

## (2) Synthesis of poly(p-tert-butoxystyrene-p-hydroxystyrene)

A solution of poly(p-tert-butoxystyrene) (15.0 g) obtained in above (1) and hydrochloric acid (10 ml) in 1,4-dioxane was refluxed for 1.5 hours with stirring. The mixture was cooled, poured into water and the 40 white solid was precipitated. The polymer was filtered, washed and dried under reduced pressure to afford 11.8 g of the title compound as white powders having \$\overline{Mw}\$10000 (GPC with polystyrene calibration). The composition of the polymer was found to be p-tert-butoxystyrene and p-hydroxystyrene in a molar ratio of ca 1:1 based on \(^1\)HNMR analysis

#### **REFERENCE EXAMPLE 2**

#### Synthesis of p-toluenesulfonylazide

After dissolving sodium azide (22.5 g, 0.35 mole) in a small amount of  $H_2O$ , the resulting solution was diluted with a 90% ethanol aqueous solution (130 ml). To this, an ethanol solution dissolving p-toluenesulfonyl chloride (60 g, 0.32 mole) was added dropwise at  $10-25^{\circ}$  C., followed by reaction at room temperature for 2.5 hours. The reaction solution was concentrated at room temperature under reduced pressure. The resulting oily residue was washed with  $H_2O$  several times and dried over anhydrous MgSO<sub>4</sub>. After removing the drying agent by filtration, there was obtained 50.7 g of the title compound as a colorless oil.

<sup>1</sup>HNMR  $\delta$  ppm (CDCl<sub>3</sub>): 2.43 (3H, s, <u>CH<sub>3</sub></u>), 7.24 (2H, <sub>65</sub> d, J=8Hz, Ar 3-H, 5-H), 7.67 (2H, d, J=8Hz, Ar 2-H, 6-H)

IR (Neat) vcm<sup>-1</sup>: 2120 (-N<sub>3</sub>).

#### EXAMPLE 1

Synthesis of bis(cyclohexylsulfonyl)diazomethane

#### (1) Synthesis of bis(cyclohexylsulfonyl)methane

To cyclohexylthiol (20.2 g, 0.17 mole), an ethanol solution dissolving potassium hydroxide (12.0 g, 0.21 mole) was added dropwise at room temperature and mixture was stirred at 30°±5° C. for 30 minutes. Then methylene chloride (18.2 g, 2.14 mole) was added to this mixture and reacted with stirring at 50°±5° C. for 6 hours. After standing at room temperature overnight, the reaction mixture was diluted with ethanol (55 ml) and added with sodium tungstate (0.4 g). Then, 30% hydrogen peroxide (50 g, 0.44 mole) was added dropwise to this solution at 45°-50° C., reacted with stirring for 4 hours at the same temperature, then added with H<sub>2</sub>O (200 ml) and standed overnight at room temperature. The precipitate was filtered, washed with H2O and dried. The resultant solid was recrystallized from ethanol to give 15.5 g of bis(cyclohexylsulfonyl)methane as white needles.

mp. 137°-139° C.

<sup>1</sup>HNMR  $\delta$  ppm (CDCl<sub>3</sub>) 1.13-2.24 (20H, m, cyclohexylic CH<sub>2</sub>×10), 3.52-3.66 (2H, m, cyclohexylic CH×2), 4.39 (2H, s, CH<sub>2</sub>).

TR (KBr-disk) v cm<sup>-1</sup>: 1320, 1305.

#### (2) Synthesis of bis(cyclohexylsulfonyl)diazomethane

To a solution of sodium hydroxide (1.7 g) in a 60% ethanol aqueous solution (70 ml), bis(cyclohexylsulfonyl)methane (12.1 g, 0.04 mole) obtained in above (1) was added, then an ethanol solution of p-toluenesulfonyl azide (8.2 g, 0.04 mole) obtained in Reference Example 2 was added dropwise at 5°-10° C., followed by the reaction at room temperature for 7 hours. After standing at room temperature overnight, the precipitate was filtered, washed with ethanol and dried. The resultant solid was recrystallized from acetonitrile to give 8.0 g of bis(cyclohexylsulfonyl)diazomethane as pale yellow prisms.

mp. 130°-131° C.

<sup>1</sup>HNMR  $\delta$  ppm (CDCl<sub>3</sub>): 1.13-2.25 (20H, m, cyclohexylic CH<sub>2</sub> $\times$ 10), 3.36-3.52 (2H, m, cyclohexylic CH<sub>2</sub>).

IR (KBr-disk) v cm<sup>-1</sup>: 2130 (CN<sub>2</sub>), 1340, 1320.
Ultraviolet spectrophotometric characteristics of bis(cyclohexylsulfonyl)diazomethane in acetonitrile solution was shown in FIG. 1. It is clear that bis(cyclohexylsulfonyl)diazomethane of the present invention

#### shows good transmittance between 240 and 300 nm. EXAMPLE 2

Synthesis of cyclohexylsulfonylethylsulfonyldiazomethane

#### (1) Synthesis of chloromethyl cyclohexylsulfide

To a mixture of cyclohexylthiol (20.2 g, 0.17 mole) and 80% paraformaldehyde (6.5 g, 0.17 mole), dry hydrogen chloride was introduced at  $-8^{\circ}-0^{\circ}$  C., then anhydrous calcium chloride was added and stirring was violently continued at 0° C. for 3 hours. After removing the precipitate by filtration, the filtrate was distilled under reduced pressure to afford 16.5 g of chloromethylcyclohexylsulfide as a colorless oil having a boiling point of  $100^{\circ}-103^{\circ}$  C./14 mmHg.

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#### (2) Synthesis of cyclohexylsulfonylethylsulfonylmethane

To ethanethiol (5.7 g, 0.09 mole), an ethanol solution dissolving potassium hydroxide (6 g, 0.09 mole) was 5 added dropwise at room temperature and mixture was stirred for 15 minutes. Then chroromethylcyclohexylsulfide (15 g, 0.09 mole) obtained in above (1) was added dropwise to this mixture at 10°±5° C. and reacted with stirring at that temperature for 3 hours. After 10 standing at room temperature overnight, the reaction mixture was diluted with ethanol (30 ml) and H<sub>2</sub>O (30 ml) and added with sodium tungstate (0.3 g). Then, 30% hydrogen peroxide (53 g, 0.47 mole) was added dropwise to this solution at  $45^{\circ}-50^{\circ}$  C., followed by reaction 15 cloride =  $8/1/0 \rightarrow 7/1/1(v/v)$ ]to give 4.1 g of cyclohexfor 6 hours at the same temperature, then added with H<sub>2</sub>O (300 ml) and standed overnight at room temperature. The precipitate was filtered, washed with H2O and dried. The resultant solid (19 g) was recrystallized from fonylmethane as white needles.

mp.: 89°-91° C.

<sup>1</sup>HNMR δ ppm (CDCl<sub>3</sub>): 1.13-2.24 (13H, m, cyclohexylic CH<sub>2</sub>×5 and CH<sub>2</sub>CH<sub>3</sub>), 3.44 (2H, q, J=7.3Hz,  $CH_2CH_3$ ), 3.53-3.68 (1H, m, cyclohexylic 25 CH), 4.40 (2H, s, CH<sub>2</sub>).

IR (KBr-disk) v cm-1: 1315.

#### (3) Synthesis of cyclohexylsulfonyl ethylsulfonyldiazomethane

To a solution of sodium hydroxide (1.7 g) in a 60% ethanol aqueous solution (70 ml), cyclohexylsulfonyle-

thylsulfonylmethane (10.2 g, 0.04 mole) obtained in above (2) was added. Then an ethanol solution of ptoluenesulfonyl azide (8.2 g, 0.04 mole) obtained in Reference Example 2 was added dropwise at 5°-10° C., followed by reaction at room temperature for 7 hours. After standing at room temperature overnight, the reaction mixture was extracted with ethyl acetate (25 ml  $\times$ 3), the organic layer was separated, washed with H<sub>2</sub>O and dried over anhydrous MgSO4. After removing the drying agent by filtration, the solvent was evaporated in vacuo, the resultant residue (12 g) was subjected to column separation [silica gel, Wakogel C-200, a trade name, manufactured by wako Pure Chemical Industries, Ltd.; eluent, n-hexane/ethyl acetate/methylene ylsulfonylethylsulfonyldiazomethane as pale yellow crystals.

m.p.: 85°-86.5° C.

<sup>1</sup>HNMR δ ppm (CDCl<sub>3</sub>): 1.13-2.27 (13H, m, cyethanol to give 15.5 g of cyclohexylsulfonylethylsul- 20 clohexylic CH2×5 and CH2CH3), 3.38-3.54 (3H, m, cyclohexylic CH and CH2CH3).

IR (KBr-disk) v cm-T: 2120 (CN<sub>2</sub>), 1325.

#### **EXAMPLES 3-5**

Using various thiol compounds of the formula (II) as a starting material, the syntheses were carried out in the same manner as described in Example 1 to give the corresponding bis(alkylsulfonyl)diazomethane. The results are summarized in Table 1.

TABLE 1

			INDUL		
Example	R1	Appearance (purification)	m.p	<sup>1</sup> HNMR δ ppm (CDCl <sub>3</sub> )	IR (KBr)
3	CH <sub>3</sub>	pale yellow needles (recrystallization from methanol)	82~84° C.	1.46(12H, d, J=7Hz, $C\underline{H}_3$ $CH \rightarrow \times 2$ )	2120 cm - 1
			,	3.74(2H, m, J=7Hz, CH <sub>3</sub> C <u>H</u> - × 2)	1340 cm <sup>-1</sup> 1320 cm <sup>-1</sup>
4	CH <sub>3</sub>       CH <sub>3</sub>   CH <sub>3</sub>	pale yellow needles (recrystallization from ethanol)	121 ~ 121.5° C.	1.52(18H, s, C <u>H<sub>3</sub></u> × 6)	2120 cm <sup>-1</sup> 1330 cm <sup>-1</sup> 1315 cm <sup>-1</sup>
5	CH <sub>3</sub> CHCH <sub>2</sub> —	pale yellow oil (column separation: silica gel, wako Gel C-200; eluent, n-hexane/ethyl acetate = 20/1)	-	1.14(12H, d, J=7Hz, -CH <sub>2</sub> CH CH <sub>3</sub> × 2)	2120 cm <sup>-1</sup>
				2.37(2H, m, CH <sub>3</sub> × 2)	
	,			CH <sub>3</sub> 3.38(4H, d, J=7HzSO <sub>2</sub> CH <sub>2</sub> CH × 2)	1350 cm <sup>-1</sup> 1330 cm <sup>-1</sup>

#### **COMPARATIVE EXAMPLE 4**

Synthesis of bis(methylsulfonyl)diazomethane

(1) Synthesis of bis(methylsulfonyl)methane

To a solution of methyl methylsulfinylmethylsulfide (7.0 g, 0.06 mole) and sodium tungsate (0.14 g) in methanol (40 ml) and H2O (4 ml), 30% hydrogen peroxide (21 g, 0.19 mole) was added dropwise at 45°-50° C., then

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Example	<b>R</b> 1	R2	Appearance (purification)	m.p.	<sup>1</sup> HNMR & ppm (CDCl <sub>3</sub> )	IR (Kbr)
6	CH <sub>3</sub> CH <sub>3</sub> CH <sub>3</sub> CH <sub>3</sub>	Сн3—	pale yellow needles (recrystallization from ethanol)	90.5∼92* C.	1.51(9H, s, —C(CH <sub>3</sub> ) <sub>3</sub> ) 3.39(3H, s, —SO <sub>2</sub> CH <sub>3</sub> )	2120 cm <sup>-1</sup> 1335 cm <sup>-1</sup> 1310 cm <sup>-1</sup>
7	CH;   	Н	pale yellow needles (recrystallization from n-hexane/ ethyl ether)	86∼88° C.	1.13-2.27(19H, m, $ \underline{H}  \underline{H}  \underline{H}  \underline{H} $ and $-C(C\underline{H_3})_3$ )	2120 cm <sup>-1</sup>
					3.47-3.63(1H, m,	1330 cm <sup>-1</sup> 1315 cm <sup>-1</sup>

#### COMPARATIVE EXAMPLES 1-3

Using various thiol compounds having a straightchain alkyl group as a starting material, the syntheses were carried out in the same manner as described in Example 1 to afford the corresponding bis(alkylsulfonyl)diazomethane. The results are summarized in Table 3.

reacted with stirring under reflux for 8 hours and standed at room temperature overnight. The reaction solution was poured into H2O (400 ml), and the precipitate was filtered, washed with H2O and dried. The resultant solid (9.5 g) was recrystallized from ethanol to afford 7.8 g of bis(methylsulfonyl)methane as white

m.p.: 148°-149.5° C. <sup>1</sup>HNMR δ ppm (CDCl<sub>3</sub>): 3.26 (6H, s, CH<sub>3</sub>×2), 4.43 (2H, s, CH<sub>2</sub>) IR (KBr-disk) v cm-1; 1310.

TABLE 3

Comparative Example	R	Appearance (purification)	m.p.	<sup>1</sup> HNMR δ ppm (CDCl <sub>3</sub> )	IR
1	C <sub>2</sub> H <sub>5</sub> —	pale yellow needles (recrystallization	88 7~89 7° C.	1 46(6H, 1, J=7.3Hz, -CH <sub>2</sub> CH <sub>3</sub> × 2)	2140 cm <sup>-1</sup>
		from methanol)		348(4H, q, J=7.3Hz, -CH2CH3 × 2)	1335 cm <sup>-1</sup>
2	CH <sub>3</sub> (CH <sub>2</sub> ) <sub>3</sub> —	pale yellow needles (column separation: silica gel,	44~47° C.	0.98(6H, t, $J=7Hz$ , — $CH_3 \times 2$ )	2145 cm <sup>-1</sup>
		Wakogel C-200, eluent, n-hexane/ ethyl acetate = 20/1		1.42-1.56(4H, m, -CH <sub>2</sub> CH <sub>3</sub> × 2)	
				1 79-1.90(4H, -SO <sub>2</sub> CH <sub>2</sub> CH <sub>2</sub> × 2)	1350 cm <sup>-1</sup>
				3.38(4H, d, $J=7Hz$ , -SO <sub>2</sub> CH <sub>2</sub> CH <sub>2</sub> - × 2)	1335 cm <sup>-1</sup>
3	CH <sub>3</sub> (CH <sub>2</sub> ) <sub>7</sub> —	pale yellow oil (column separation:	_	0.82-1.94(30H. m CH <sub>3</sub> (CH <sub>2</sub> ) <sub>6</sub> × 2)	2120 cm <sup>-1</sup>
		silica gel, Wakogel C-200; eluent, n-hexane/ ethyl acetate = 3/1		$343(4H. t, -SO_2CH_2- \times 2)$	1340 cm <sup>-1</sup>

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#### (2) Synthesis of bis(methylsulfonyl)diazomethane

Using bis(methylsulfonyl)methane (7.5 g, 0.04 mole) obtained in above (1), the reaction was carried out in the same manner as described in Example 1, (2), and the 5 crude solid (4.5 g) was chromatographed on silica gel (Wakogel C-200) with n-hexane/ethyl acetate (8/1 →  $4/1 \rightarrow 3/1$ ) as eluent to give 2.5 g of bis(methylsulfonyl)diazomethane as white crystals.

m.p.: 120°-124° C.

<sup>1</sup>HNMR  $\delta$  ppm (CDCl<sub>3</sub>): 3.37 (6H, s, CH<sub>3</sub>×2). IR (KBr-disk) v cm<sup>-1</sup>: 2145 (CN<sub>2</sub>), 1335, 1320.

#### APPLICATION EXAMPLE 1

was prepared:

Poly(p-tert-butoxystyrene-p-	6.0 g	
hydroxystyrene)		20
[Polymer obtained in Reference		
Example 1, (2)]		
Bis(cyclohexylsulfonyl)diazomethane	0.3 g	
[Photoacid generator obtained in		
Example 1, (2)]		
Diethylene glycol dimethyl ether	13 7 g	25

Using the resist material, a pattern was formed as shown in FIG. 2. That is, the resist material was spin coated on a substrate 1 such as a 6 inch silicon wafer in diameter and prebaked by a hot plate at 90° C. for 90 30 seconds to give a resist material film 2 of 1.0 μm thick [FIG. 2 (a)]. The film 2 was selectively exposed to KrF excimer laser light 3 of 248.4 nm via a mask 4 at a dose of 25 mJ/cm<sup>2</sup> using a projection aligner (5:1 reduction, NA = 0.42) [FIG. 2 (b)]. The exposed film was heated at 35 110° C. for 90 seconds, then development was carried out using a conventional alkali aqueous solution (2.38% tetramethylammonium hydroxide aqueous solution) for 60 seconds to remove exposed regions of the film 2 by dissolution to give a positive pattern 2a without loss of 40 film thickness in the unexposed regions [FIG. 2(c)]. The positive pattern had an aspect ratio of ca. 87 degree and 0.3 µm lines and spaces were resolved.

#### APPLICATION EXAMPLES 2 to 7

Resist materials were prepared in the same manner as described in Application Example 1 except for using the diazodisulfone compounds obtained in Examples 2 to 7 as the photoacid generator. Patterns were formed on semiconductor substrates in the same manner as de. 50 bis(cyclohexylsulfonyl)diazomethane, scribed in Application Example 1. The results are shown in Table 4.

TABLE 4

plication	Photoacid generator	Exposure energy amount (mJ/cm <sup>2</sup> )	Resolution (µm L/S)	
 2	Example 3	25	0.3	
3	Example 4	25	0.3	
4	Example 5	30	03	
5	Example 2	30	0.3	
6	Example 6	30	0.3	
7	Example 7	25	0.3	

As is clear from Table 4, good positive tone patterns 65 are formed by using the resist materials containing the compound of the formula (I) as the photoacid genera-

#### REFERENCE EXAMPLES 3 to 6

Resist materials were prepared in the same manner as described in Application Example 1 except for using the bis(straight-chain alkylsulfonyl)diazomethanes obtained in Comparative Examples 1 to 4. Using the resist materials, patterns were tried to form on semiconductor substrates in the same manner as described in Application Example 1, but no positive tone patterns were formed, 10 since non-exposed portions were dissolved at the time of development.

These results show that the compounds of the formula (I) of the present invention obtained by introducing a bulky alkyl group into at least one of R1 and R2 A resist material having the following composition 15 moisties of the formula (I) play an important role to exhibit dissolution inhibiting effect for the alkali developing solution.

As mentioned above, when the photosensitive resist materials containing the diazodisulfone compounds of 20 the formula (I) of the present invention are used for a light source of 300 nm or less such as deep UV light, KrF excimer laser light (248.4 nm), etc., fine patterns with good shapes of submicron order can easily be obtained.

The compound of the formula (I) of the present invention exhibits remarkable effects as the photoacid generator when exposed to not only deep UV light, KrF excimer laser light, but also ArF excimer laser light, electron beams, and X-rays.

What is claimed is:

1. A diazodisulfone compound of the formula:

$$R^{1}SO_{2}CSO_{2}R^{2}$$
 $N_{2}$ 
(I)

wherein R1 is a branched or cyclic alkyl group having 3 to 8 carbon atoms; and R<sup>2</sup> is a straight-chain, branched or cyclic alkyl group having 1 to 8 carbon atoms.

2. A diazodisulfone compound according to claim 1, wherein R1 is a cyclopentyl group, a cyclohexyl group, an isopropyl group, a sec-butyl group, a tert-butyl group or an isoamyl group; and R2 is a methyl group, an ethyl group, a cyclopentyl group, a cyclohexyl group, 45 an isopropyl group, a sec-butyl group, a tert-butyl group or an isoamyl group.

3. A diazodisulfone compound according to claim 1,

cyclohexylsulfonylethylsulfonyldiazomethane, bis(isopropylsulfonyl)diazomethane, bis(tert-butylsulfonyl)diazomethane, bis(sec-butylsulfonyl)diazomethane, tert-butylsulfonylmethylsulfonyldiazomethane, tert-butylsulfonylcyclohexylsulfonyldiazomethane, bis(cyclopentylsulfonyl)diazomethane, cyclopentylsulfonyl-tert-butylsulfonyldiazomethane, or bis(isoamylsulfonyl)diazomethane.

4. A diazodisulfone compound of the formula:

wherein R1 is a branched or cyclic alkyl group having 3 to 8 carbon atoms; and R2 is a branched or cyclic alkyl group having 3 to 8 carbon atoms.



5. A compound according to claim 4, wherein  $R^{\dagger}$  is a branched alkyl group having 3 to 8 carbon atoms; and  $R^2$  is a branched alkyl group having 3 to 8 carbon atoms.

6. A compound according to claim 4, wherein R1 is a

cyclic alkyl group having 3 to 8 carbon atoms; and R2 is

a cyclic alkyl group having 3 to 8 carbon atoms.

7. A compound according to claim 4 wherein R is a branched alkyl group having 3 to 8 carbon atoms; and R<sup>2</sup> is a cyclic alkyl group having 3 to 8 carbon atoms.

Adiazodisilfone compound of the formula

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60

65

## 8. A diazodisulfone compound of the formula;

$$\begin{array}{c} \underline{R^1SO_2CSO_2R^2} \\ \parallel \\ \underline{N_2} \end{array}$$

wherein  $R^1$  is a cyclic alkyl group in which the alkyl group is hexyl; and  $R^2$  is a cyclic alkyl group in which the alkyl group is hexyl.

## 9. A diazodisulfone compound of the formula;

$$\begin{array}{c} \underline{R^1SO_2CSO_2R^2} \\ \parallel \\ \underline{N_2} \end{array}$$

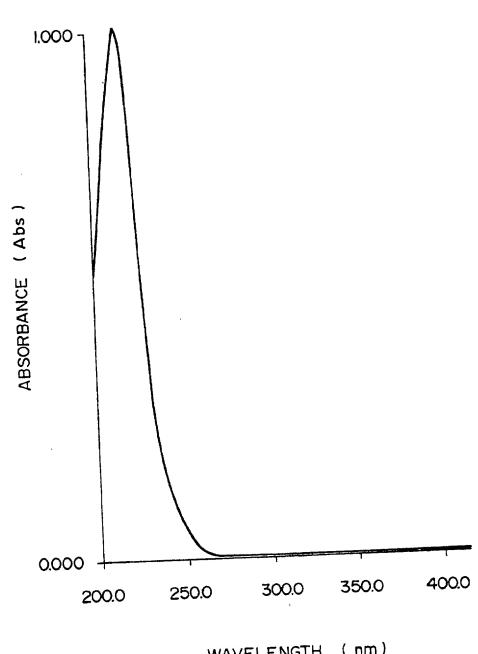
where R<sup>1</sup> is a branched alkyl group in which the alkyl group is butyl; and R<sup>2</sup> is a

branched alkyl group in which the alkyl group is butyl.

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WAVELENGTH (nm)



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